NSN 5961-01-339-3272

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-339-3272 **Inclosure Material:** Glass **Overall Length:** 3.04 millimeters **Terminal Length:** 25.4 millimeters **Overall Diameter:** 1.6 millimeters **End Application:** Tactical air operations central an/tyq-2 (v) 1 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-34 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 reverse voltage, dc **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset **Capacitance Rating In Picofarads:** 10.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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